Photovoltaic Effects Exhibited in High-resistance Semi-conducting Films

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Semi-conducting rims MICROCRYSTALLINE layers of lead sulphide have been obtained which, after suitable activation, exhibit photovoltaic effects of a new type. The photosensitive layer consists of a film about 1 micron in thick-ness deposited on glass between graphite electrodes a few millimetres apart. When illuminated by infra-red radiation of wave-length between approximately 1 and 3-5 microns, a photo E.M.F. is developed between the electrodes. It has been shown that this effect is inde-pendent of the contacts between the semi-conductor and the electrodes, and is due to the internal properties of the sensitive material. Cells with resistance of a few megohms and photo E.M.F. is developed between reductive groperties, the ratio of conductivities for opposite directions of current being about 100: 1 at room temperature. The photo current is always in the direction of high resistance. The cells were produced as a result of information obtained during development work on the photoconductivity of activated thal con-ductivity in semi-conductors is associated with the presence of im-purity centres in the crystalline lattice. The impurity centres may be either electro-positive or electro-negative, giving rise respectively to 'electronic' or hole' components of conductivity. Consideration of our results obtained from sensitizing treatments in oxygen and *in eacuo* leads to the conclusion that impurity centres of cither sign may be introduced, and further support is given to this by measurements of the Hall coefficient. High conductivity due to the presence of impurity of one sign alone is not associated with photosensitivity. The best photoconductivity in a given layer appears when maximum resistance is obtained, which may be explained by the existence of some kind of equilibrium between impurity centres of both signs which are simultaneously present. Also the corportinental results are best explained by the assumption that the positive and negative concentration are closely associa

pronounced. Under certain conditions, non-uniform activation across the cell may be obtained; and it is found that the photovoltaic and photo-conductive sensitivity are always associated with the same part of the layer, as would be expected from the above considerations. Also in exceptional cases the sensitive area can be displaced across the layer towards the positive electrode, indicating the mobility of negative centres and a fairly uniform distribution of positive centres. A full description of the experimental work and a more detailed development of the theoretical considerations will be given elsewhere. J. STARKIEWICZ L. SOSNOWSKI O. SIMPSON

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Surface Area Determination

In the determination of surface area using nitrogen at the tempera-ture of liquid nitrogen by the method of Brunauer, Emmeth and Teller¹, it is usual to determine the dead-space on each sample, using helium. For routine determinations on a substance known to give S-shaped isotherms, that is, where the equation of Brunauer, Emmett and Teller is applicable, it is possible to avoid this dead-space determ-ination. If V_1 c.c. nitrogen are adsorbed at a pressure p_1 , then the dead-space is given by

$$p_1 (1 + \alpha)D \simeq p_1 D_2$$

where D is dead-space at unit pressure and a is a correction factor equal to 6.58×10^{-5} at unit pressure. Hence, if V_{c_1} is volume of nitrogen in the sample bulb, then

 $V_1 = V_{c1} - p_1 D; V_2 = V_{c2} - p_2 D; V_3 = V_{c3} - p_3 D.$ It follows that

$$V_1 = V_{c1} - p_1 \left(\frac{V_{c3} - V_3}{p_3} \right).$$

Emmett² points out that a line drawn through the origin and one adsorption point at a relative pressure of c. 0.3 usually differs in slope by less than 5 per cent from that drawn using several adsorption variates. points.

 $V_1 (p_0 - p_1) = V_2 (p_0 - p_2) = V_3 (p_0 - p_3).$ Therefore

$$V_1 = V_{c_1} - \frac{p_1}{p_3} \left(V_{c_3} - V_1 \cdot \frac{p_0 - p_1}{p_0 - p_3} \right).$$

Rearranging,

$$V_{1} = \frac{V_{c_{1}} - V_{c_{3}} \frac{p_{1}}{p_{3}}}{1 - \frac{p_{1}}{p_{3}} \left(\frac{p_{0} - p_{1}}{p_{0} - p_{3}}\right)};$$

and similarly for V_2 .

In the plot of p/p_0 against $\frac{p}{V(p_0-p)}$, the monolayer volume V_m is the reciprocal of the slope, that is,

$$V_m = \frac{(p_2 - p_1)/p_0}{p_2/\{V_2(p_0 - p_2)\} - p_1/\{V_1(p_0 - p_1)\}}.$$
 (1)

This involves determining three adsorption points, but no dead-space : a slightly less accurate value can be found using only two points, that is,

$$V_m = rac{p_1/p_0}{p_1/\{V_1(p_0 - p_1)\}} = rac{V_1}{p_0}(p_0 - p_1).$$

In neither case is it necessary actually to plot the points. Areas determined on various substances by the usual technique, that is, involving a dead-space determination, are compared with those obtained by recalculation using equation (1) above in the following table:

	Area in sq. m./gm.	
Substance .	By dead-space determination	By recalculation
Carbon A	790	753
Carbon B	847	840
Carbon C	814	800
Carbon D	460	460
Carbon E	280	282
Chalk A	30	29
Chalk B	19	19
Paris White	2	2
Clay	10	10
Asbestos	18	14

It will be noted that the calculated areas are generally lower than the dead-space areas, that is, the slopes are too great: this is in accordance with the assumption made above. Our thanks are due to the directors of the Washington Chemical Company, Ltd., for permission to publish this note.

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Brunauer, Emnett and Teller, J. Amer. Chem. Soc., 60, 309 (1938).
Emmett, P. H., "Symposium on New Methods of Determining Particle Size in Subsieve Range", Amer. Soc. Test. Mat., p. 95 (March 1941).

An Optical-Acoustic Method of Gas Analysis

An Optical-Acoustic Method of Gas Analysis Bell, Tyndall and Röntgen all knew that gases and vapours absorb infra-red rays and that they would produce sounds if a stream of rays was interrupted at sonic frequencies. The mechanism of this heated and its pressure increases. If the stream of radiation is inter-rupted at sonic frequency, there are rapid changes of pressure in the gas. Pulsation takes place, which is nothing more nor less than sound. The pitch of the sound depends on the frequency at which the rays are interrupted, and its strength on the ability of the gas to absorb infra-red rays. If pure air, in which there are no extraneous gases or vapours, is submitted to interrupted irradiation with infra-red rays, there will be no sound, since oxygen and nitrogen, of which the air is composed, do not absorb infra-red rays. If the rays are passed through a mixture greater the quantity of extraneous matter present in the air. Tyndall first spoke of using this phenomenon to detect gases in mines so early as 1888. He had at his disposal no instrument with which to measure the strength of sounds, and could not therefore put his idea into practice. The idea of using interrupted infra-red rays for this purpose was forgotten until 1937, when I developed my optical-acoustic gas analyser, involving the use of modern reception and measuring instruments. This analyser will determine the quantita-is already known. The method is almost universal and will detect all gases except oxygen, hydrogen and nitrogen, which do not absorb infra-red rays.

are emitted by an electrically heated platinum ribbon in a closed box with a window through which rays pass. They are inter-